



#### 20V P-Channel Enhancement Mode MOSFET

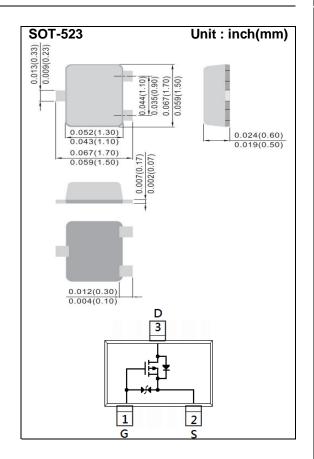
Voltage -20 V Current -500mA

#### **Features**

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Load switch, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

#### **Mechanical Data**

- Case: SOT-523 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00007 ounces, 0.002 grams
- Marking: E07



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

| PARAMETER   |                      | SYMBOL          | LIMIT       | UNITS |
|---|----------------------|-----------------|-------------|-------|
| Drain-Source Voltage                                      |                      | $V_{DS}$        | -20         | V     |
| Gate-Source Voltage                                       |                      | $V_{GS}$        | <u>+</u> 10 | V     |
| Continuous Drain Current                                  |                      | I <sub>D</sub>  | -500        | mA    |
| Pulsed Drain Current                                      |                      | I <sub>DM</sub> | -1000       | mA    |
| Power Dissipation   | T <sub>a</sub> =25°C | P <sub>D</sub>  | 300         | mW    |
|   | Derate above 25°C    |                 | 2.4         | mW/°C |
| Operating Junction and Storage Temperature Range          |                      | $T_J, T_{STG}$  | -55~150     | °C    |
| Typical Thermal resistance - Junction to Ambient (Note 3) |                      | $R_{	heta JA}$  | 417         | °C/W  |





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

| PARAMETER   | SYMBOL              | TEST CONDITION   | MIN. | TYP.       | MAX.        | UNITS       |  |
|---|---------------------|--|------|------------|-------------|-------------|--|
| Static  |                     |  |      |            |             |             |  |
| Drain-Source Breakdown Voltage                        | $BV_{DSS}$          | V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA  | -20  | -          | ı           | <b>V</b>    |  |
| Gate Threshold Voltage                                | $V_{GS(th)}$        | $V_{DS}=V_{GS}$ , $I_{D}=-250uA$   | -0.3 | -0.59      | -1.0        | V           |  |
| Drain-Source On-State Resistance                      | R <sub>DS(on)</sub> | V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-500mA   | -    | 0.9        | 1.2         | Ω           |  |
|   |                     | V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-200mA   | -    | 1.07       | 1.5         |             |  |
|   |                     | V <sub>GS</sub> =-1.8V, I <sub>D</sub> =-100mA   | -    | 1.25       | 2.2         |             |  |
|   |                     | V <sub>GS</sub> =-1.5V, I <sub>D</sub> =-40mA  | -    | 1.42       | 3.6         |             |  |
|   |                     | V <sub>GS</sub> =-1.2V, I <sub>D</sub> =-10mA  | -    | 1.7        | 6.0         |             |  |
| Zero Gate Voltage Drain Current                       | I <sub>DSS</sub>    | V <sub>DS</sub> =-16V, V <sub>GS</sub> =0V   | -    | -          | -1          | uA          |  |
| Gate-Source Leakage Current                           | I <sub>GSS</sub>    | $V_{GS}=\pm 8V, V_{DS}=0V$   | -    | <u>+</u> 2 | <u>+</u> 10 | uA          |  |
| Dynamic (Note 5)                                      |                     |  |      |            |             |             |  |
| Total Gate Charge                                     | $Q_g$               | V <sub>DS</sub> =-10V, I <sub>D</sub> =-500mA,<br>V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup> | -    | 1.4        | -           | nC          |  |
| Gate-Source Charge                                    | $Q_{gs}$            |  | -    | 0.19       | -           |             |  |
| Gate-Drain Charge                                     | $Q_{gd}$            |  | -    | 0.2        | -           |             |  |
| Input Capacitance                                     | Ciss                | V <sub>DS</sub> =-10V, V <sub>GS</sub> =0V,  | -    | 38         | ı           | pF          |  |
| Output Capacitance                                    | Coss                |  | -    | 15         | ı           |             |  |
| Reverse Transfer Capacitance                          | Crss                | f=1.0MHZ   | -    | 9          | ı           |             |  |
| Turn-On Delay Time                                    | td <sub>(on)</sub>  | $V_{DD}$ =-10V, $I_{D}$ =-500mA, $V_{GS}$ =-4.5V, $R_{G}$ =6 $\Omega$ (Note 1,2)               | -    | 7.2        | -           | ns          |  |
| Turn-On Rise Time                                     | tr                  |  | -    | 21         | ı           |             |  |
| Turn-Off Delay Time                                   | td <sub>(off)</sub> |  | -    | 85         | ı           |             |  |
| Turn-Off Fall Time                                    | tf                  |  | -    | 116        | -           |             |  |
| Drain-Source Diode                                    |                     |  |      |            |             |             |  |
| Maximum Continuous Drain-Source Diode Forward Current | I <sub>S</sub>      |  | -    | -          | -500        | mA          |  |
| Diode Forward Voltage                                 | $V_{SD}$            | I <sub>S</sub> =-500mA, V <sub>GS</sub> =0V  | -    | -0.93      | -1.3        | <b>&gt;</b> |  |

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Reja is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.





#### TYPICAL CHARACTERISTIC CURVES

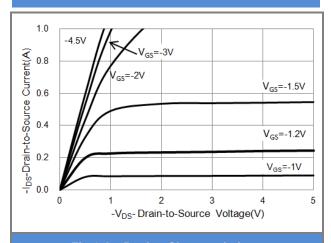
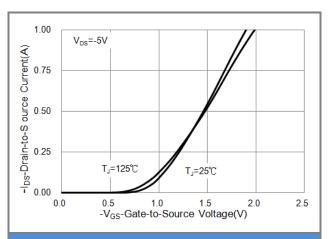


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

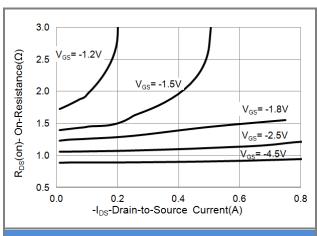


Fig.3 On-Resistance vs. Drain Current

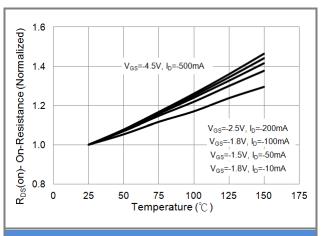


Fig.4 On-Resistance vs. Junction temperature

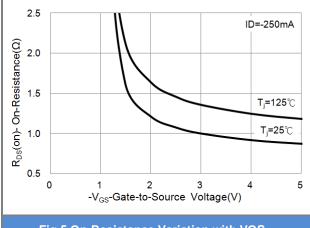
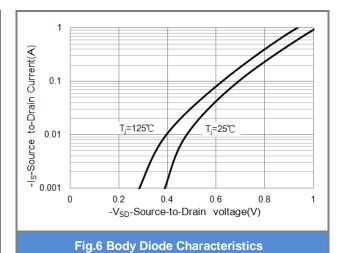


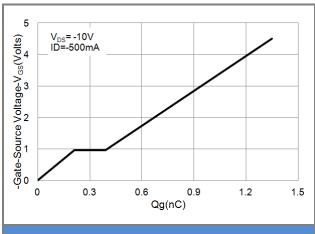
Fig.5 On-Resistance Variation with VGS.







#### TYPICAL CHARACTERISTIC CURVES



**Fig.7 Gate-Charge Characteristics** 

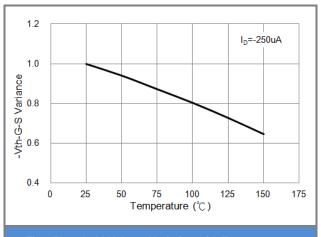


Fig.8 Threshold Voltage Variation with Temperature

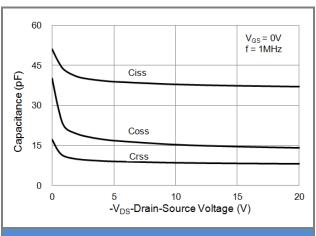


Fig.9 Capacitance vs. Drain-Source Voltage

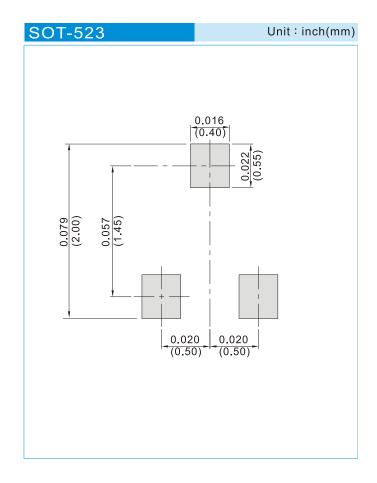




#### PART NO PACKING CODE VERSION

| Part No Packing Code | Package Type | Packing type     | Marking | Version      |
|----------------------|--------------|------------------|---------|--------------|
| PJE8407_R1_00001     | SOT-523      | 4K pcs / 7" reel | E07     | Halogen free |

### **MOUNTING PAD LAYOUT**







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